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INVESTIGATING THE PHYSICAL AND MECHANICAL PROPERTIES OF TIO₂ VARISTOR MATERIALS PREPARED WITH VARIOUS DOPANTS

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ABSTRACT

Varistors are the most efficient devices for the protection of power transmission lines and electronic devices against excessive transient surges. The current trends that require varistors with more functions have led to research to develop new ceramic varistor material and titanium dioxide (TiO₂) is the emerging new material. In this research nanosized TiO₂ was taken as the base materials to which a small amount of impurities was added as dopants for enhancing the properties. Ta₂O₅, WO₃, Bi₂O₃ and Co₃O₄ were used as dopants where the percentage of Bi₂O₃ and Co₃O₄ was fixed; 0.5% and 0.2% respectively. Samples were prepared with different weight percentages of dopants and sintered at a constant temperature of 1300°C with 2 hour's holding time to observe the effect of these dopants on physical and mechanical properties of nanosized TiO₂. Analysis was undertaken to evaluate the properties of the nanosized TiO₂, such as green density, fired density, fired strength, axial and radial shrinkage. It was found that with the composition of 98.1% $TiO_2+0.7\%$ $Ta_2O_5+0.5\%$ $WO_3+0.2\%Co_3O_4+0.5\%Bi_2O_3$ have a significant influence on the physical and mechanical properties, which is anticipated to improve the performance of varistor. With the improvement in the physical and mechanical properties of TiO₂, the composite material has potential application in low voltage application devices.

Keywords: TiO₂ varistor; dopants; fired density; fired strength; hardness.

INTRODUCTION

Varistor is a ceramic material which has unique nonlinear current-voltage characteristics, and is used in circuit to protect the system against transient surge voltage. The most important characteristic of varistor is its nonlinear current voltage behavior that can be expressed by the equation $I=KV^{\alpha}$, where α is the nonlinear coefficient (Santana, Dos Santos, Sousa, & Chui, 2008). A higher value of this coefficient signifies a better device. Ceramics such as silicon carbide, zinc oxide (ZnO), and tin dioxide (SnO₂) are some of the varistors studied before (Keating & Nesic, 1999). Up to now, ZnO has been the most extensively studied due to its excellent properties, so as to be employed in both the power industry and the semiconductor industry, and shown high nonlinear coefficient than SiC (Choon, 2012). However, the

use of TiO₂ as a semiconductor is relatively new and research is ongoing to improve its functional properties. Investigation shows that current trends require varistor to have a low capacitance and low breakdown voltage, thus the use of ZnO varistor is restricted in low voltage circuits due to its low permittivity, which weakens its ability to absorb sparks (Luo, Tang, Li, & Zhang, 2008). Titanium dioxide (TiO₂), also known as titania, is a versatile material with a high density (4.0 g/cm³) and very low percentage of porosity that has attracted many due to properties that can satisfy the new functional demand.

In study to develop a useful TiO₂ based ceramic, it is important to investigate the effect of dopants on varistor performance. Up until now, study of TiO2 was based on either one or two dopants to increase its properties and performance. Addition of dopants should promote properties of nanosized TiO₂ to increase electrical conductivity through a process of crystallization. Titanium dioxide has been investigated since 1982, by (Yan & Rhodes, 1982) who first reported the nonlinear coefficient for (Nb, Ba) doped TiO_2 ceramic varistor around $\alpha=3-4$ and that an oxidizing atmosphere during cooling would be necessary. According to previous researchers, tantalum pentaoxide (Ta₂O₅) and tungsten trioxide (WO₃) act as substantial donors and increase the electrical conductivity of TiO2. It was observed that a high nonlinear coefficient and low breakdown voltage could be obtained by addition of Ta₂O₅ into the system (Luo et al., 2008). Furthermore, the addition of WO₃ would cause the formation of a solid solution with TiO₂ lattice due to ionic similarity, thus influencing the grain growth of TiO₂ (Su et al., 2003; Wang et al., 2012). On the other hand, cobalt (II,III) oxide (Co₃O₄) was reported as one of the effective dopants that promotes densification of TiO₂, as it creates oxygen vacancies, increases oxygen diffusion at grain boundaries, and promotes densification (Metz et al., 2007). Meanwhile, the addition of bismuth(III) oxide (Bi₂O₃), should promote the growth of TiO₂ grains and the stability of the nonlinear current-voltage by providing the medium for liquid-phase sintering (Wang et al., 2012; Xu, Cheng, Yuan, Yang, & Lin, 2011). There is still a lack of research and study on the effect of the addition of Bi₂O₃ to a TiO₂ powder based varistor. Although there are previous researchers who have studied the effect of various dopants towards the electrical properties of the TiO₂ powder based varistor, there is still a lack of research done on the physical, mechanical, and microstructural properties of nanosize TiO₂ based varistor. In this study the effect of dopants on the properties of TiO₂ ceramic was therefore examined.

EXPERIMENTAL WORK

Nano size of titanium dioxide (TiO₂) based varistor with the appropriate percentage of weights dopants was prepared as shown in Table 1. The percentage of Co₃O₄ (ALDRICH), and Bi₂O₃ (ALDRICH) remained constant, and the percentage of Ta₂O₅ (ALDRICH) and WO₃ (ALDRICH) varied throughout the experiment. The mixing composition was ball milled with zirconia balls and ethanol as solvent inside a jar for one hour. The slurry produced was dried in an oven at 60°C for 24 hours. The resulting powder was sieved and pelletized into disks 20mm in diameter and 4mm thick at uniaxial pressure, 2.76MPa. The green pellet was sintered at a constant temperature of 1300°C for two hours and cooled at constant rate of 10°C/min. Samples were polished using different sizes of abrasives, followed by diamond paste, and carefully washed in water. The properties of TiO₂ were investigated by calculating the density and the shrinkage rate of the sample. The fired densities were determined after sintering with

the Archimedes Method. Axial and radial shrinkage were also calculated based on the dimension of the pellet. For mechanical properties, the sintered strength was calculated using a Vickers hardness test machine; the Wolpert Wilson Instrument model. Samples was coated with gold to identify microstructural characterization using Scanning Electron Microscope (SEM) model Hitachi S-3400N to determine the porosity and grain size using the intercept method. The average grain size, G, was calculated with Eq.(1):

$$G = \text{Number of intercepts}' \text{ Line length}$$
 (1)

The ceramic phases were identified by X-Ray Diffraction model Shimadzu XRD-6000 using Cu K α radiation. The samples were scanned in 2θ ranges of 20-60 $^{\circ}$ for the period of a 0.02 step scan mode.

Samples	Composites (wt%)
A	TiO_2
В	$TiO_2 + 0.2wt\% Ta_2O_5 + 0.25wt\% WO_3 + 0.2wt\% Co_3O_4 + 0.5wt\% Bi_2O_3$
C	TiO ₂ +0.2wt % Ta ₂ O ₅ +0.5wt% WO ₃ +0.2wt% Co ₃ O ₄ +0.5wt % Bi ₂ O ₃
D	TiO ₂ +0.4wt % Ta ₂ O ₅ +0.1wt % WO ₃ +0.2wt % Co ₃ O ₄ +0.5wt % Bi ₂ O ₃
E	TiO ₂ +0.7wt % Ta ₂ O ₅ +0.5wt % WO ₃ +0.2wt % Co ₃ O ₄ +0.5wt % Bi ₂ O ₃

Table 1. Composition of Samples.

RESULTS AND DISCUSSION

Green Density and Fired Density

The variation of density with the different composition of nanosized TiO_2 based varistor disc is presented in Figure 1. It can be seen that the results of densification after the sintering process was highly dependent on the concentrations of dopants. According to Figure 1, the increment in fired density shows the trend in general, becoming more densified with the increments in the concentration of dopants. These are due to the behavior of Ta_2O_5 and WO_3 , which formed a solid solution with the TiO_2 lattice at high temperature, thus increasing the density of nanosized TiO_2 .

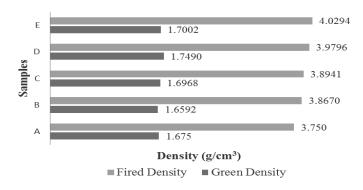


Figure. 1. Green and fired density of TiO₂ disc with different concentration of dopants.

Moreover, the addition of WO₃ influences grain growth, and thus influences the density of the samples. The addition of Co₃O₄ should promote densification of nanosized TiO₂, with an influence similar to that of CoO over SnO₂ (Metz et al., 2007).

Only with the addition of Ta_2O_5 and WO_3 content around 0.7% and 0.5%, did the samples exhibit high fired density (4.0294 g/cm³), which is 0.7% higher compared to a theoretical density of TiO_2 (4.000 g/cm³).

Axial and Radial Shrinkage

To determine the shrinkage rate of nanosized TiO₂, the thickness and diameter of pellets were measured before and after the sintering process. The percentage of thickness and diameter reduction was calculated with the following Eq. 2 and Eq. 3:

$$\%t = \left[\left(\frac{\delta t}{t_g} \right) \times 100\% \right] \tag{2}$$

$$\%d = \left[\left(\frac{\delta d}{d_g} \right) \times 100\% \right]$$
 (3)

where *t* is the thickness of the pellet, *d* is diameter of the pellet.

Figure 2 and Figure 3 present the axial and radial shrinkage rate at different dopant concentrations. Sample E shows the average highest reduction of other samples. It is well documented that the maximum shrinkage rate is highly dependent on the concentration of dopants (Wang, Tang, Yua, & Cao, 2011). The increase in Ta_2O_5 and WO3 has a great influence on the sintering process of the system. At maximum shrinkage temperature (1300 °C), highly doped samples cause segregation at grain boundaries which results in a decrease in grain size, and thus will increase the strength of the samples (Navale, Vadivel Murugan, & Ravi, 2007)

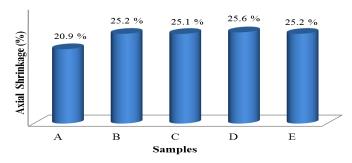


Figure. 2. Axial shrinkage (%) TiO₂ disc with different concentration of dopants.

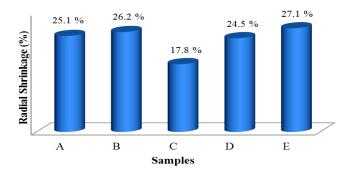


Figure. 3. Radial shrinkage (%) TiO₂ disc with different concentration of dopants.

Sintered Strength

The hardness values of ceramic material are frequently analyzed to characterize resistance to deformation as well as densification, despite poor performance on ceramic material due to experimental issues such as cracking or chipping. However, it is important to observe whether a small impurity added to TiO₂ can increase the mechanical properties to relate it with electrical behavior of the material. The sintered strength was determined by using a Vickers hardness test by allowing the diamond-tipped fall into the sample to observe the maximum load that samples can withstand without causing damage. As shown in Figure 4, Sample E, which previously showed the highest density apparently shows highest hardness values as well. Sample E, TiO₂ doped with 0.7% Ta₂O₅, 0.5% WO₃, 0.2% Co₃O₄ and 0.5% Bi₂O₃, has comparatively higher hardness values compared to other samples (805.05 HV1). Furthermore, compressive strength also been conducted to calculate the compressive strength of the nanosized TiO₂. As shown in Figure 5, once again Sample E shows the highest values of compressive strength.

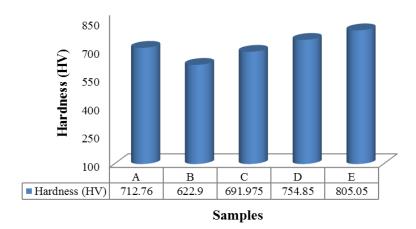


Figure 4. Hardness Values of TiO₂ with different concentration of dopants.

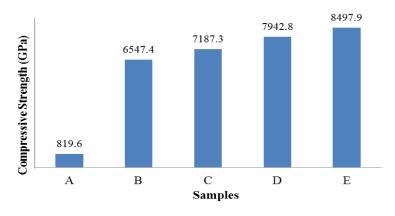


Figure 5. Compressive Strength of TiO₂ with different concentration of dopants.

Scanning Electron Microscope

Figure 6 shows the SEM micrograph of the compact TiO₂ with different concentrations at 1300°C. The strength of samples was further confirmed by SEM micrograph. Grain size gradually decreases as the concentration of dopants increases, thus increasing the

strength of the sample. The average grain size obtained through the linear intercept method was in the range of 2-10 μ m. The mean grain size decreased as concentrations of Ta_2O_5 and WO_3 increased, which shows that the increment in dopants prevented the grain from growing. This is in agreement with other findings for high performance varistors (Filho et al., 2007; Silva et al., 2007; Xu et al., 2011). From Figure 6 it can also be seen that porosity reduced with the addition of dopants, thus increasing the physical and mechanical properties of TiO_2 .

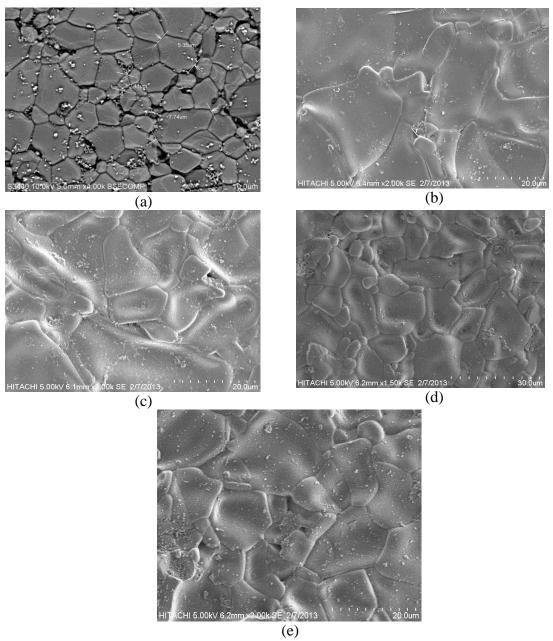


Figure 6. Microstucture of nanosized TiO_2 (a) 100% TiO_2 (b) $0.2\%Ta_2O_5+0.25\%WO_3$, (c) $0.2\%Ta_2O_5+0.5\%WO_3$, (d) $0.4\%Ta_2O_5+0.1\%WO_3$, (e) $0.7\%Ta_2O_5+0.5\%WO_3$.

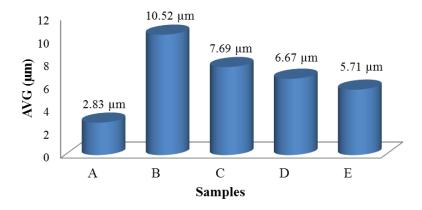


Figure 6. Average grain size (μm) of TiO₂ discs with different concentrations of dopants.

X-Ray Diffraction

In order to investigate the phase structure of the $TiO_{2, an}$ XRD test was carried out. The pattern showed perfectly that all diffraction peaks indexed to a rutile TiO_2 when scanned at 2θ ranges of $20^\circ - 60^\circ$ for the period of the 0.0200 step scan mode. No phases other than TiO_2 were observed. This could be because the amount of dopants added was very low and other possible phases may not been detected due to equipment limitations. This is in agreement with other studies. Major intensity peaks for the rutile phase of nanosized TiO_2 with $2\theta = 27.54^\circ$, 36.17° and 54.42° are clearly seen.

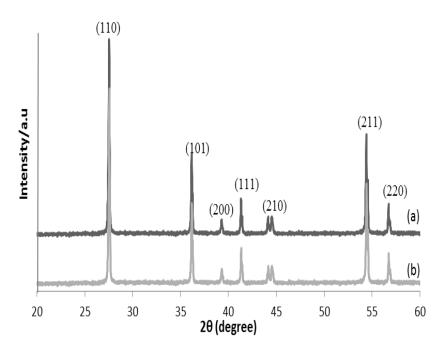


Figure 7 : XRD of TiO₂ disc (a) 100% TiO₂ (b) 0.7%Ta₂O₅+0.5%WO₃+0.2wt%Co₃O₄+0.5wt %Bi₂O₃

CONCLUSIONS

The physical, mechanical and microstructure of nanosized TiO_2 doped with various dopants were evaluated. The addition of dopants significantly influenced the properties of TiO_2 varistor discs. The varistor discs prepared with 0.7% Ta_2O_5 , 0.5% WO_3 , 0.2% Co_3O_4 and 0.5% Bi_2O_3 exhibited improved properties compared to other compositions. The enhancement in strength of the nanosized TiO_2 signifies the reduction of porosity and enhancement of density of TiO_2 based ceramic varistor. Physical, mechanical and microstructure results evidence the influence of the dopants on the processing of TiO_2 powder at high temperature. Furthermore, influences on grain size and porosity will facilitate the performance of varistor.

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